

View Online at <https://aerobasegroup.com/nsn/5961-01-467-8058>

Inclosure Material:

Metal

Mounting Facility Quantity:

8

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 drain to source voltage and 20.0 gate to source voltage

Current Rating Per Characteristic:

3.50 amperes source cutoff current of standard range

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-emitter absolute

Maximum Operating Temperature Per Measurement Point:

-55.0 degrees celsius case and 150.0 degrees celsius case

Special Features:

Metal oxide field effect transistor

Terminal Type And Quantity:

8 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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